

View Online at <https://aerobasegroup.com/nsn/5961-00-430-6884>

**Inclosure Material:**

Plastic

**Overall Length:**

Between 0.660 inches and 0.785 inches

**Overall Height:**

0.200 inches

**Overall Width:**

Between 0.290 inches and 0.310 inches

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Press fit

**Features Provided:**

Hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

50.0 collector to emitter voltage/static/base open all transistor and 80.0 collector to base voltage, dc all transistor and 80.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 6.0 emitter to base voltage, instantaneous all transistor

**Current Rating Per Characteristic:**

1.50 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

750.0 milliwatts small-signal input power, common-collector absolute all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction

**Special Features:**

All transistor junction pattern arrangement: npn

**Terminal Type And Quantity:**

14 ribbon

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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